Main and Fringe Field Computations for the Electrostatic Quadrupoles of the Muon g-2 Experiment Storage Ring

Eremey Valetov^{1,2} and Martin Berz¹

¹Michigan State University, East Lansing, MI 48824, USA ²Lancaster University and the Cockcroft Institute, UK

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• Methods for measurement of anomalous MDM and EDM using storage rings rely on electrostatic particle optical elements.

- Accordingly, it is necessary to accurately model main and fringe fields of electrostatic elements.
- In particular, inaccurate treatment of fringe fields of electrostatic elements provides a mechanism for energy conservation violation.



Main and Fringe Fields of the Muon g-2 Collaboration Quadrupole

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Section 1

Fringe Fields of Electrostatic Deflectors

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Conformal Mappings



The Schwarz–Christoffel mapping $f(z) = \sqrt{z}$ maps the upper half-plane to the upper-right quadrant of the complex plane. (Image source: Kapania *et al.*)

- A conformal mapping (or conformal map) is a transformation f : C → C that is locally angle-preserving.
- Conformal mappings satisfy Cauchy-Riemann equations, which is useful for solving the Laplace equation.

Fringe Fields of Semi-Infinite Capacitors

- Using conformal mappings, we obtained electrostatic field falloffs for semi-infinite capacitors with infinitely thin, infinitely thick, and finitely thick plates, including plates with rounded edges.
- There is a good agreement with fringe fields of several finite rectangular electrostatic capacitors obtained using a boundary element method (BEM) field solver.



Comparison of field falloffs of several semiinfinite capacitors computed in the SC Toolbox with field falloffs of two finite rectangular capacitors computed in COULOMB.

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Fringe Fields of Two Adjacent Semi-Infinite Capacitors



The plot on the left shows the electrostatic field and equipotential lines of two adjacent semi-infinite capacitors with plates of 3D/4 thickness, symmetric voltages, and rounded edges. The plot on the right shows the electrostatic field $E_{A\&B}(z)$ (blue) of two adjacent semi-infinite capacitors with plates of D/2 thickness and different voltages $V_A = 1$ and $V_B = 3$, individual fields $E_A(z)$ (orange) and $E_B(z)$ (green) of each capacitor as in empty space, and the difference $E_{A\&B}(z) - E_B(z)$ (dashed red) that would be equal to $E_A(z)$ without electrostatic induction.

We also modeled fringe fields of two adjacent semi-infinite capacitors with finitely thick plates and symmetric, antisymmetric, and different voltages.

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Accurate Fringe Fields Representation

- We found that the field falloff of an electrostatic deflector is slower than exponential.
- Enge functions of the form $F_N(z) = \frac{1}{1 + \exp\left(\sum_{j=1}^N a_j\left(\frac{z}{D}\right)^{j-1}\right)}$ are not suitable for accurate modeling of the asymptotic behavior of said falloffs.
- We found that the alternative function

$$H(z) = \frac{1}{1 + \exp\left[\sum_{j=1}^{N_1} a_j \left(\frac{z}{D}\right)^{j-1}\right]} \frac{1}{1 + \exp\left[\left(\frac{z}{D} - c\right)^2\right]} + \frac{1}{\sum_{j=1}^{N_2} b_j \left(\frac{z}{D}\right)^{j-1}} \frac{1}{1 + \exp\left[-\left(\frac{z}{D} - c\right)^2\right]}$$

models field falloffs of electrostatic deflectors accurately.

Accurate Fringe Fields Representation



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Section 2

Main and Fringe Fields of the Muon *g*-2 Collaboration Quadrupole

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Main Field of the Muon g-2 Collaboration Quadrupole

The main field of an electrostatic element such as the Muon g-2 collaboration quadrupole may be obtained using the following method:

- Calculate the electrostatic potential using conformal mapping methods with one plate at 1 V and the other Dirichlet boundary conditions (the remaining plates, the rectangular enclosure, and the trolley rails) of 0 V.
- Apply plate distance errors as perturbations to four copies of the potential, each copy corresponding to one plate at 1 V and the other Dirichlet boundary conditions of 0 V.
- Apply appropriate rotations to these four copies of the potential, scale the copies (e.g., by ±2.4 × 10⁴ or with mispowered values), and use their superposition.



The Muon g-2 collaboration quadrupole. (Image source: Semertzidis *et al.*)



The Muon ring at Fermilab. (Image source: FNAL.)

Nominal Symmetric and Non-Symmetric Models



The plots on the left and right show the polygonal model of the Muon g-2 collaboration quadrupole in the SM and NSM cases, respectively.

- We considered two polygonal models of the cross section: (1) the nominal case with symmetric voltages and no geometric asymmetries ("SM"), and (2) the general case of mispowered plates and geometric asymmetries ("NSM").
- In the former case, the polygonal model is simplified using reflection and rotation symmetries.

In both cases, the derivative of the conformal mapping f from the canonical domain to the physical domain is

$$f'(z) = c \operatorname{cn}(z|m) \operatorname{dn}(z|m) \prod_{j=1}^{n} (\operatorname{sn}(z|m) - \operatorname{sn}(x_j + iy_j|m))^{\alpha_j - 1},$$

where sn, cn, and dn are the Jacobi elliptic functions¹, K is the complete elliptic integral of the first kind², the parameters *n* and α were obtained from the polygonal model, and the parameters *x*, *y*, *m*, and *c* were found using the *SC Toolbox*.

¹Definitions of the Jacobi elliptic functions can be found at http://mathworld.wolfram.com/JacobiEllipticFunctions.html. ²The complete elliptic integral of the first kind is defined at http://mathworld.wolfram.com/ CompleteEllipticIntegraloftheFirstKind.html.

Multipole Terms



The plot on $\vec{the} = e^{2}$ hows a hearmap plot of the multipole expansion of the electrostatic potential in the NSM case, up to order 24. The plot on the right shows a contour plot of the multipole expansion of the electrostatic potential in the NSM case, orders 3 to 24.

- We obtained the multipole expansion of the electrostatic potential using the differential-algebraic (DA) inverse of the conformal mapping, as well as using Fourier analysis applied to the conventional inverse.
- The conformal mappings method has the advantage of an analytic, fully Maxwellian formula and allows rapid recalculations with adjustments to the geometry and mispowered plates.
- The applicability of the conformal mapping method is limited by the crowding phenomenon; it can be expanded to more complex geometries using the cross ratios of the Delaunay triangulation (CRDT) algorithm.

Fringe Field of the Muon g-2 Collaboration Quadrupole

- We obtained the quadrupole strength falloff and the EFB z_{EFB} = 1.2195cm for the Muon g-2 collaboration quadrupole by calculating Fourier modes of its electrostatic potential at a set of radii in the transversal plane.
- The electrostatic potential data was obtained using a BEM field solver from a 3D model of the quadrupole.
- For a confirmatory comparison, we applied the same method of calculating multipole strengths to the electrostatic field data obtained for the Muon g-2 collaboration quadrupole using *Opera-3d*'s finite element method (FEM) field solver by Wanwei Wu (FNAL).



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Results Based on Soltner-Valetov and Wu Field Data



The falloff of the multipole term $M_{2,2}$ agrees well between calculations based on Soltner–Valetov field data ($z_{\rm EFB} = 1.2195$ cm; solid blue) and field data by Wu ($z_{\rm EFB} = 1.1233$ cm; dashed red).

- The field falloffs and the EFBs obtained from Soltner-Valetov and Wu field data are in good agreement, and so are the tunes based on them.
- The quadrupole strength and the EFBs we obtained using this method explained the experimentally measured tunes, while simple estimates based on a linear model exhibited discrepancies up to 2%.

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